IN THE CLAIMS:

1. (Previously Presented) A gain-clamped semiconductor optical amplifier comprising:

a gain waveguide for amplifying an optical signal input to the gain waveguide; and

a grating layer having a first grating on a portion of the grating layer, the first grating

being disposed at a first end portion,

wherein the gain waveguide is disposed on the grating layer in a direct contact with the

first grating.

2. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 1,

further comprising a second grating disposed at a second end portion.

3. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 1,

further comprising a clad laminated on the gain waveguide.

4. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 2,

wherein the first and the second gratings have reflection factors different from each other.

5. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 1,

wherein the gain waveguide includes a mode conversion region formed at one end portion of the

gain waveguide, the mode conversion region having a width which becomes narrower or wider

as it goes to an end adjacent to the semiconductor optical amplifier.

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- 6. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 5, wherein the mode conversion region is not in contact with the first grating.
- 7. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 5, wherein the mode conversion region is in contact with a portion of the first grating.
- 8. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 2, wherein the gain waveguide includes mode conversion regions formed at both sides of the gain waveguide, the mode conversion regions having a width which becomes narrower or wider as it goes to a corresponding end of the semiconductor optical amplifier.
- 9. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 8, wherein the mode conversion regions are not in contact with the first and the second gratings.
- 10. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 8, wherein each of the mode conversion regions are in contact with a portion of a grating adjacent to the mode conversion region.
- 11. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 1, further comprising non-reflection layers disposed on two portions of the semiconductor optical amplifier.

- 12. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 2, further comprising non-reflection layers disposed on two portions of the semiconductor optical amplifier.
- 13. (Original) The gain-clamped semiconductor optical amplifier as claimed in claim 1, further comprising:
- a non-reflection layer disposed on a first end surface of the semiconductor optical amplifier, the first end surface serving as an input/output side of the semiconductor optical amplifier; and
- a high reflection layer disposed on a second end surface of the semiconductor optical amplifier.
 - 14. (Previously Presented) A semiconductor optical amplifier comprising:
- a gain waveguide arranged to amplify an optical signal input to the gain waveguide, the optical signal being input and an amplified optical signal being output through a first end surface of the semiconductor optical amplifier; and
 - a grating layer having a grating on a portion of the grating layer,
- wherein the gain waveguide is disposed on the grating layer in a direct contact with the grating.
- 15. (Original)The semiconductor optical amplifier as claimed in claim 14, wherein the grating layer has another grating on another portion of the grating layer.

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- 16. (Original) The semiconductor optical amplifier as claimed in claim 15, wherein grating and the another grating have reflection factors different from each other.
- 17. (Original) The semiconductor optical amplifier as claimed in claim 14, wherein the gain waveguide includes at least one mode conversion region.